# 3A, 18V, 500KHz, Synchronous Step-Down DC/DC Converter

#### **FEATURES**

- 4.75V to 18V input voltage
- Output adjustable from 0.923V to 15V
- Output current up to 3A
- Integrated  $105m\Omega/85m\Omega$  power MOSFET switches
- Shutdown current 3μA typical
- Efficiency up to 95%
- Fixed frequency 500KHz
- Internal soft start
- Over current protection and Hiccup
- Over temperature protection
- RoHS Compliant and 100% Lead (Pb) Free

#### **APPLICATIONS**

- Distributed power systems
- Networking systems
- FPGA, DSP, ASIC power supplies
- Notebook computers
- Green electronics or appliance

#### **DESCRIPTION**

The ZTP7193SI is a high-frequency, synchronous, rectified, step-down, switch-mode converter with internal power MOSFETs. It offers a very compact solution to achieve a 3A continuous output current over a wide input supply range, with excellent load and line regulation. The ZTP7193SI has synchronous-mode operation for higher efficiency over the output current-load range.

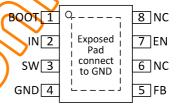
Current-mode operation provides fast transient response and eases loop stabilization.

Protection features include over-current protection and thermal shutdown.

The ZTP7193SI requires a minimal number of readily available, standard external components and is available in a space saving SOP-8L(EP) package.

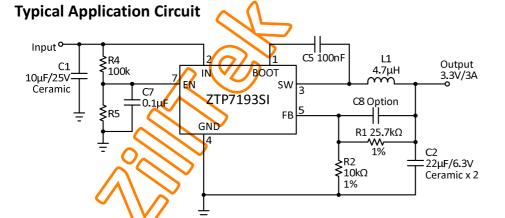
# Pins Configuration





## **ORDERING INFORMATION**

PART	PACKAGE	RoHS	Ship, Quantity
ZTP7193SI	SOP-8L (EP)	Yes	Tape and Reel



Note: R5 and C7 are optional.

Details please see the DVT report.



## **Absolute Maximum Ratings**

Supply Voltage V <sub>IN</sub>	0.3V to +20V
Switch Node V <sub>SW</sub>	0.3V to V <sub>IN</sub> +0.3V
Boost V <sub>BOOT</sub>	V <sub>SW</sub> -0.3V to V <sub>SW</sub> +6V
All Other Pins	–0.3V to +6V
Junction Temperature	+150°C
Lead Temperature	+260°C
Storage Temperature Range	65°C to +150°C

**CAUTION**: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

# **Electro-Static Discharge Sensitivity**

This integrated circuit can be damaged by ESD.

It is recommended that all integrated circuits
be handled with proper precautions. Failure

to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure.

## **Recommended Operating Conditions**

Supply Voltage V <sub>IN</sub>	4.75V to 18V
Output Voltage V <sub>OUT</sub>	0.923V to V <sub>IN</sub> –3V
<b>Operating Temperature Range</b>	40°C to +125°C

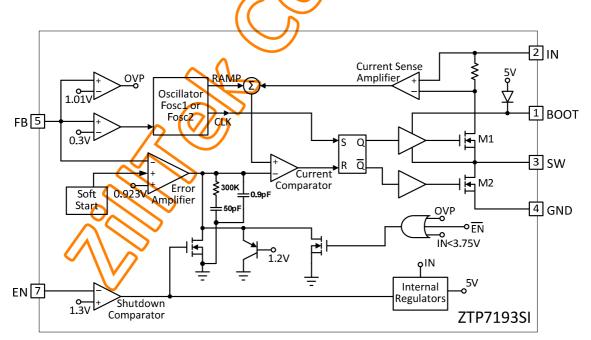
## **Package Thermal Characteristics**

Thermal Resistance, $\theta_{JA}$	<u> </u>	 50°C/W
Thermal Resistance, $\theta_{JC}$		-

## **Pins Description**

Pin	Symbol	Description
1	BOOT	High-side gate drive boost input.
2	IN	Power input.
3	SW	Power switching output.
4	GND	Ground.
5	FB	Feedback input.
6	NC	Not connected.
DO.	Ĕ	Enable input.
8	26	Not connected.

# **Functional Block Diagram**

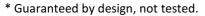




## **Electrical Specifications**

 $(T_A = +25$ °C,  $V_{IN} = +12V$ , unless otherwise noted.)

PARAMETER	Symbol	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V <sub>IN</sub>		4.75		18	V
Output Voltage	V <sub>OUT</sub>		0.923		15	V
Shutdown Supply Current		V <sub>EN</sub> = 0V		3	6	μΑ
Supply Current		V <sub>EN</sub> = 2.0V, V <sub>FB</sub> = 1V		0.09		mA
Feedback Voltage	$V_{FB}$	4.75V ≤ V <sub>IN</sub> ≤ 18V	0.900	0.923	0.946	V
Feedback Over-voltage Threshold				1.01	2	V
Error Amplifier Voltage Gain *	A <sub>EA</sub>		0	1000		V/V
Error Amplifier Transconductance	$G_{EA}$	$\Delta I_C = \pm 10 \mu A$		40		μA/V
High-Side Switch-On Resistance *	R <sub>DS(ON)1</sub>		SY	105		mΩ
Low-side Switch-On Resistance *	R <sub>DS(ON)2</sub>			<b>8</b> 5		mΩ
High-Side Switch Leakage Current		$V_{EN} = 0V, V_{SW} = 0V,$ $T_{A} = +125^{\circ}C$		,	10	μΑ
Upper Switch Current Limit		Minimum Duty Cycle	3.7	4.3		Α
Lower Switch Current Limit		From Drain to Source	<i>(</i> )	0		Α
Oscillation Frequency	F <sub>osc1</sub>		400	500	600	KHz
Short Circuit Oscillation Frequency	F <sub>osc2</sub>	V <sub>FB</sub> = 0V	100	125	150	KHz
Maximum Duty Cycle	D <sub>MAX</sub>	$\gamma_{FB} = 0.5 V$		90		%
Minimum On Time *				120		ns
EN Falling Threshold Voltage		V <sub>EN</sub> Falling		1.22		V
EN Rising Threshold Voltage		V <sub>EN</sub> Rising		1.32		V
Input Under Voltage Lockout Threshold		V <sub>IN</sub> Rising		3.75		V
Input Under Voltage Lockout Threshold Hysteresis		0)		200		mV
Soft-Start Period	((	)		16		ms
Thermal Shutdown *		7		150		°C

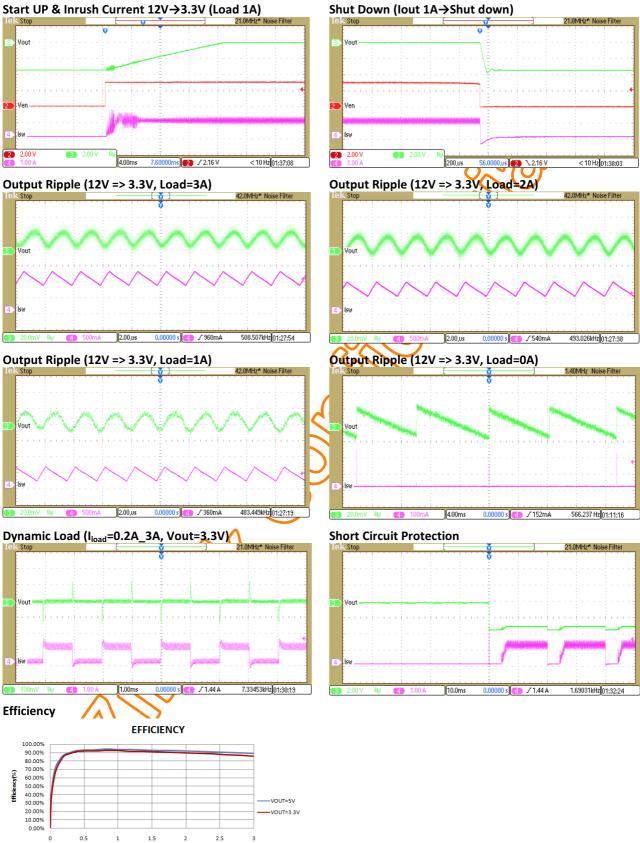






## **Typical Characteristics**

 $V_{IN}$  = 12V,  $V_{O}$  = 3.3V, L1 = 4.7 $\mu$ H, C1 = 10 $\mu$ F, C2 = 22 $\mu$ F x 2,  $T_{A}$  = +25°C, unless otherwise noted.



Load Current(A)



#### **APPLICATION INFORMATION**

#### Overview

The ZTP7193SI is a synchronous rectified, current-mode, step-down regulator. It regulates input voltages from 4.75V to 18V down to an output voltage as low as 0.923V, and supplies up to 3A of load current.

The ZTP7193SI uses current-mode control to regulate the output voltage. The output voltage is measured at FB through a resistive voltage divider and amplified through the internal transconductance error amplifier.

The converter uses internal N-Channel MOSFET switches to step-down the input voltage to the regulated output voltage. Since the high side MOSFET requires a gate voltage greater than the input voltage, a boost capacitor connected between SW and BOOT is needed to drive the high side gate. The boost capacitor is charged from the internal 5V rail when SW is low.

When the ZTP7193SI FB pin exceeds 10% of the nominal regulation voltage of 0.923V, the over voltage comparator is tripped, forcing the high-side switch off.

## **Pins Description**

**BOOT:** High-Side Gate Drive Boost Input. BOOT supplies the drive for the high-side N-Channel MOSFET switch. Connect a  $0.1\mu F$  or greater capacitor from SW to BOOT to power the high side switch.

IN: Power Input. IN supplies the power to the IC, as well as the step-down converter switches. Drive IN with a 4.75V to 18V power source. Bypass IN to GND with a suitably large capacitor to eliminate noise on the input to the IC.

**SW:** Power Switching Output. SW is the switching node that supplies power to the output. Connect the output LC filter from SW to the output load. Note that a capacitor is required from SW to BOOT to power the high-side switch.

GND: Ground.

**FB:** Feedback Input. FB senses the output voltage to regulate that voltage. Drive FB with a resistive voltage divider from the output voltage. The feedback threshold is 0.923V.

**EN:** Enable Input. EN is a digital input that turns the regulator on or off. Drive EN high to turn on the regulator, drive it low to turn it off. Pull up with  $100k\Omega$  resistor for automatic startup.

## **Setting the Output Voltage**

The output voltage is set using a resistive voltage divider from the output voltage to FB pin. The voltage divider divides the output voltage down to the reedback voltage by the ratio:

$$V_{FB} = V_{OUT} \times R2 / (R1 + R2)$$

Where  $V_{FB}$  is the feedback voltage and  $V_{OUT}$  is the output voltage.

Thus the output voltage is:

$$V_{OUT} = 0.923 \times (R1 + R2) / R2$$

R2 can be as high as  $100k\Omega$ , but a typical value is  $10k\Omega$ . Using the typical value for R2, R1 is determined by:

$$R1 = 10.83 \times (V_{OUT} - 0.923V) (K\Omega)$$

## Inductor

The inductor is required to supply constant current to the output load while being driven by the switched input voltage. A larger value inductor will result in less ripple current that will result in lower output ripple voltage. However, the larger value inductor will have a larger physical size, higher series resistance, and/or lower saturation current. A good rule for determining the inductance to use is to allow the peak-to-peak ripple current in the inductor to be approximately 30% of the maximum switch current limit. Also, make sure that the peak inductor current is below the maximum switch current limit. The inductance value can be calculated by:

$$L = [V_{OUT} / (f_S \times \Delta I_L)] \times (1 - V_{OUT} / V_{IN})$$

Where  $V_{OUT}$  is the output voltage,  $V_{IN}$  is the input voltage,  $f_S$  is the switching frequency, and  $\Delta I_L$  is the peak-to-peak inductor ripple current.

Choose an inductor that will not saturate under the maximum inductor peak current. The peak inductor current can be calculated by:

$$I_{LP} = I_{LOAD} + [V_{OUT} / (2 \times f_S \times L)] \times (1 - V_{OUT} / V_{IN})$$

Where  $I_{\text{\tiny LOAD}}$  is the load current.

The choice of which style inductor to use mainly depends on the price vs. size requirements and any EMI requirements.

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## **Optional Schottky Diode**

During the transition between high-side switch and low-side switch, the body diode of the low-side power MOSFET conducts the inductor current. The forward voltage of this body diode is high. An optional Schottky diode may be paralleled between the SW pin and GND pin to improve overall efficiency. Table 1 lists example Schottky diodes and their Manufacturers.

Part Number	Voltage and Current Rating	Vendor	
B130	30V, 1A	Diodes Inc.	
SK13	30V, 1A	Diodes Inc.	
MBRS130	30V, 1A	International Rectifier	

Table 1: Diode selection guide.

#### **Input Capacitor**

The input current to the step-down converter is discontinuous, therefore a capacitor is required to supply the AC current to the step-down converter while maintaining the DC input voltage. Use low ESR capacitors for the best performance. Ceramic capacitors are preferred, but tantalum or low-ESR electrolytic capacitors may also suffice. Choose X5R OF X7R dielectrics when using ceramic capacitors.

Since the input capacitor (C1) absorbs the input switching current it requires an adequate ripple current rating. The RMS current in the input capacitor can be estimated by:

$$I_{C1} = I_{LOAD} \times [(V_{OUT}/V_{IN}) \times (1 - V_{OUT}/V_{IN})]^{1/2}$$

The worst-case condition occurs at  $V_{IN} = 2V_{OUT}$ , where  $I_{C1} = I_{LOAD}/2$ . For simplification, choose the input capacitor whose RMS current rating greater than half of the maximum load current

The input capacitor can be electrolytic, tantalum or ceramic. When using electrolytic or tantalum capacitors, a small, high quality ceramic capacitor, i.e.  $0.1\mu F$ , should be placed as close to the IC as possible. When using ceramic capacitors, make sure that they have enough capacitance to provide sufficient charge to prevent excessive voltage ripple at input. The input voltage ripple for low ESR capacitors can be estimated by:

$$\Delta V_{IN} = [I_{LOAD}/(C1 \times f_S)] \times (V_{OUT}/V_{IN}) \times (1 - V_{OUT}/V_{IN})$$
  
Where C1 is the input capacitance value.

## **Output Capacitor**

The output capacitor is required to maintain the DC output voltage. Ceramic, tantalum, or low ESR electrolytic capacitors are recommended. Low ESR capacitors are preferred to keep the output voltage ripple low. The output voltage ripple can be estimated by:

$$\Delta V_{OUT} = [V_{OUT}/(f_S \times L)] \times (1 - V_{OUT}/V_{NL})$$
$$\times [R_{ESR} + 1/(8 \times f_S \times C2)]$$

Where C2 is the output capacitance value and  $R_{ESR}$  is the equivalent series resistance (ESR) value of the output capacitor.

In the case of ceramic capacitors, the impedance at the switching frequency is dominated by the capacitance. The output voltage ripple is mainly caused by the capacitance. For simplification, the output voltage ripple can be estimated by:

$$\Delta V_{QUT} = [V_{QUT}/(8 \times f_s^2 \times L \times C2)] \times (1 - V_{QUT}/V_{IN})$$

In the case of tantalum or electrolytic capacitors, the ESR dominates the impedance at the switching frequency. For simplification, the output ripple can be approximated to:

$$\Delta V_{OUT} = [V_{OUT}/(f_S \times L)] \times (1 - V_{OUT}/V_{IN}) \times R_{ESR}$$

The characteristics of the output capacitor also affect the stability of the regulation system. The ZTP7193SI can be optimized for a wide range of capacitance and ESR values.

## **External Bootstrap Diode**

An external bootstrap diode may enhance the efficiency of the regulator, the applicable conditions of external BOOT diode are:

- V<sub>OUT</sub> = 5V or 3.3V; and
- Duty cycle is high: D = V<sub>OUT</sub>/V<sub>IN</sub> > 65%

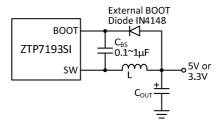


Figure 1: Add optional external bootstrap diode to enhance efficiency.

In these cases, an external BOOT diode is recommended

from the output of the voltage regulator to BOOT pin, as shown in Figure 1.

The recommended external BOOT diode is IN4148, and the BOOT capacitor is 0.1  $^{\sim}$  1 $\mu$ F.

When  $V_{IN} \le 6V$ , for the purpose of promote the efficiency, it can add an external Schottky diode between IN and BOOT pins, as shown in Figure 2.

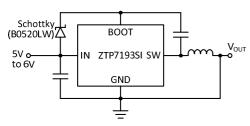


Figure 2: Add a Schottky diode to promote efficiency when  $V_{\text{IN}} \leq 6V$ .

## **PCB Layout Guide**

PCB layout is very important to achieve stable operation. Please follow the guidelines below.

1) Keep the path of switching current short and minimize the loop area formed by Input capacitor,

- high-side MOSFET and low-side MOSFET.
- 2) Bypass ceramic capacitors are suggested to be put close to the  $V_{\text{IN}}$  Pin.
- 3) Ensure all feedback connections are short and direct.

  Place the feedback resistors and compensation components as close to the chip as possible.
- 4) Rout SW away from sensitive analog areas such as
- 5) Connect IN, SW, and especially GND respectively to a large copper area to cool the chip to improve thermal performance and long-term reliability.

## BOM of ZTP71938N

Please refer to the Typical Application Circuit.

Item	Reference	Part
1	(O91)	10μF
2	C5	100nF
3	C7	0.1μF
Q <sub>1</sub>	R4	100K

Table 2: BOM selection table I.

	L1	R1	R2	53	C8
Vout = 5.0V	6.8µH	44.2K	10K	22μ <b>F</b> ×2	100pF
Vout = 3.3V	4.7μΗ	25.7K	<b>1</b> 0K	22μF×2	100pF
Vout = 2.5V	4.7μΗ	17.1K	10K	22μF×2	50pF
Vout = 1.8V	3.3μΗ	9.50K	10K	22μF×2	50pF
Vout = 1.2V	2.2μΗ	3.00K	10K	22μF×2	20pF
Vout = 1.0V	2.2μΗ	0.834K	10K	22μF×2	20pF

Table 3: BOM selection table II.

# PACKAGE DIMENSIONS SOP-8L (EP)

